

### **Product Summary**

**Description and Applications** 

**Engine Management Systems Body Control Electronics** 

BV <sub>DSS</sub>	Rds(on) max	l⊳ max Tc = +25°C
C0)/	11mΩ @ V <sub>GS</sub> = 10V	47.6A
60V	16mΩ @ V <sub>GS</sub> = 4.5V	39.5A

This MOSFET is designed to meet the stringent requirements of

automotive applications. It is qualified to AEC-Q101, supported by a

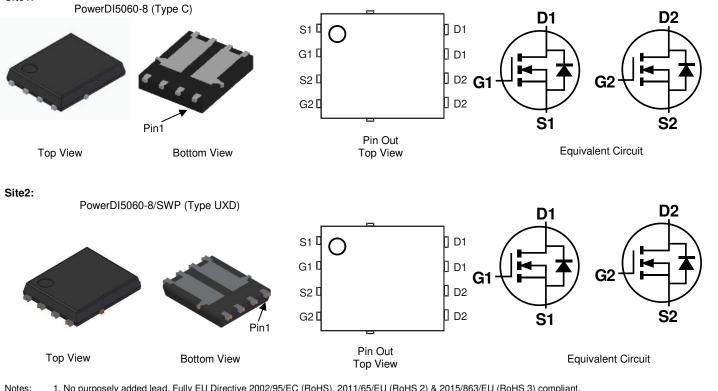
#### **Features and Benefits**

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching (UIS) Test in Production -Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DMTH6010LPDQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

### **Mechanical Data**

- Package: PowerDI<sup>®</sup>5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.097 grams (Approximate)



1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

PowerDI is a registered trademark of Diodes Incorporated.

Site1:

PPAP and is ideal for use in:

**DC-DC Converters** 

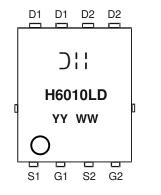


## Ordering Information (Note 4)

Part Number	Paakana	Packing		
Part Number	Package	Qty.	Carrier	
DMTH6010LPDQ-13	PowerDI5060-8 (Type C)	2,500	Tape & Reel	
DMTH6010LPDQ-13	PowerDI5060-8/SWP (Type UXD)	2,500	Tape & Reel	

Notes: 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

# **Marking Information**



DH = Manufacturer's Marking H6010LD = Product Type Marking Code YYWW or  $\overline{YY}$  = Date Code Marking YY or  $\overline{YY}$  = Year (ex: 21 = 2021) WW = Week (01 to 53)

### **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	60	V
Gate-Source Voltage			Vgss	±20	V
Continuous Drain Current (Note 6) $T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$		ID	47.6 33.7	A	
Continuous Drain Current (Note 5)	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	13.1 10.9	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			ldм	170	А
Maximum Continuous Body Diode Forward Current (Note 6)			ls	31	А
Avalanche Current, L = 0.1mH			IAS	20	А
Avalanche Energy, L = 0.1mH			Eas	20	mJ

# **Thermal Characteristics**

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	TA = +25°C	PD	2.8	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	53	°C/W
Total Power Dissipation (Note 6)	Tc = +25°C	PD	37.5	W
Thermal Resistance, Junction to Case (Note 6)		Rejc	4	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

 Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Thermal resistance from junction to soldering point (on the exposed drain pad). Notes:



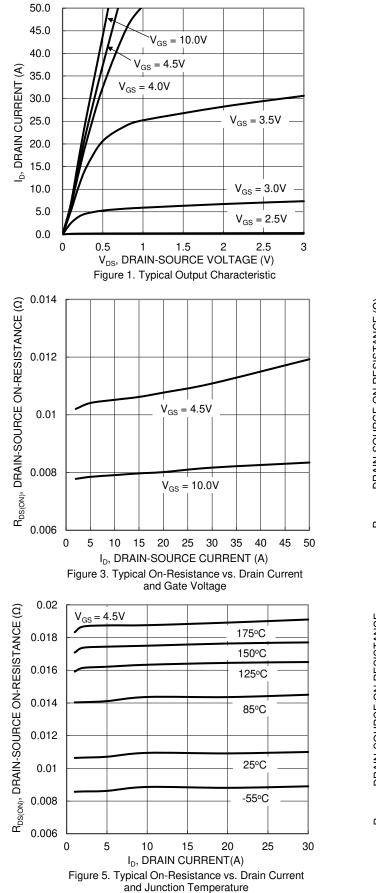
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

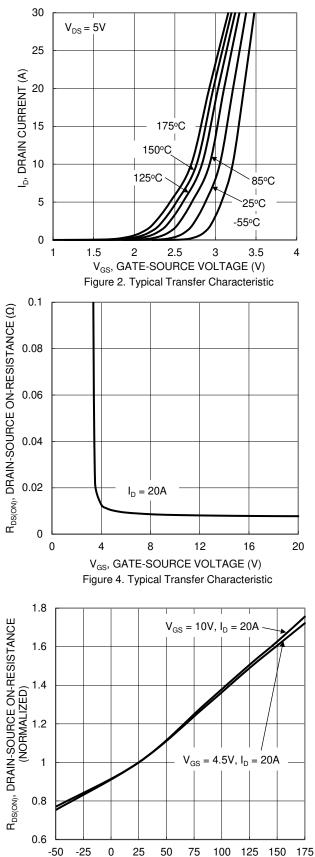
						-	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BVDSS	60	—		V	$V_{GS} = 0V, I_D = 1mA$	
Zero Gate Voltage Drain Current	IDSS	_	_	1	μΑ	$V_{DS} = 48V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)						-	
Gate Threshold Voltage	VGS(TH)	1		3	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Pro/on	—	8.5	11	mΩ	$V_{GS} = 10V, I_{D} = 20A$	
Static Drain-Source On-Resistance	RDS(ON)	—	10.9	16	11152	$V_{GS} = 4.5V, \ I_D = 20A$	
Diode Forward Voltage	Vsd	_	0.9	1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 20A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	—	2615	—	pF	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V, f = 1MHz	
Output Capacitance	Coss	—	1415	_	pF		
Reverse Transfer Capacitance	Crss	_	58	_	pF		
Gate Resistance	Rg	—	0.67	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V <sub>GS</sub> = 4.5V)	Qg	_	20.3	_	nC		
Total Gate Charge (V <sub>GS</sub> = 10V)	Qg	_	40.2	_	nC		
Gate-Source Charge	Qgs	_	5.9	_	nC	V <sub>DS</sub> = 30V, I <sub>D</sub> = 20A	
Gate-Drain Charge	Q <sub>gd</sub>	_	9.3	_	nC	1	
Turn-On Delay Time	t <sub>D(ON)</sub>	_	5.7		ns		
Turn-On Rise Time	tR	_	8.8		ns	$V_{DD} = 30V, V_{GS} = 10V,$ $I_D = 20A, R_G = 3\Omega$	
Turn-Off Delay Time	tD(OFF)	_	20.8		ns		
Turn-Off Fall Time	tF	_	7.4		ns	7	
Body Diode Reverse Recovery Time	trr	—	34.5		ns		
Body Diode Reverse Recovery Charge	QRR		37.5		nC	I <sub>F</sub> = 20A, di/dt = 100A/µs	

 Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:



## DMTH6010LPDQ

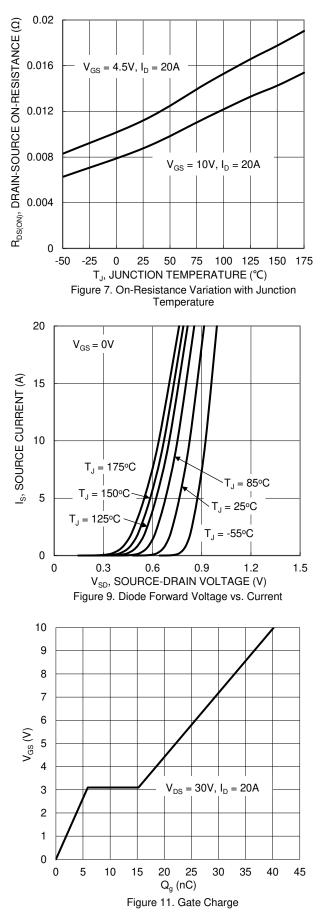


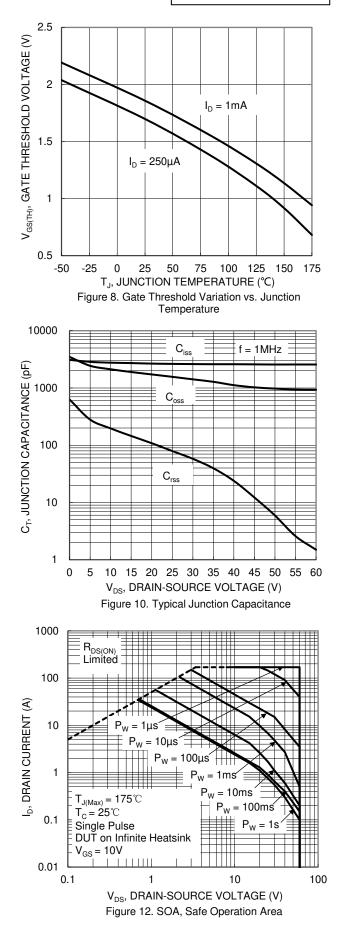


T<sub>J</sub>, JUNCTION TEMPERATURE (°C) Figure 6. On-Resistance Variation with Junction Temperature



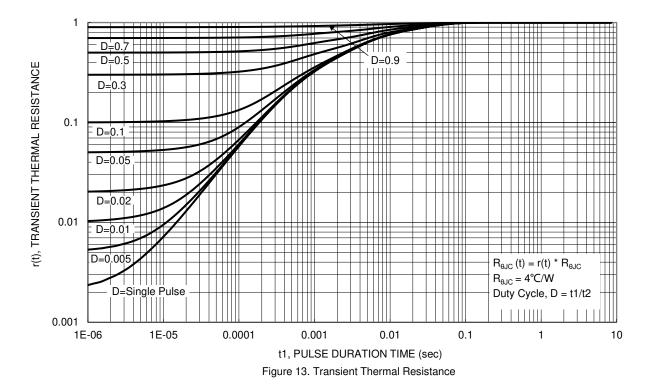
## DMTH6010LPDQ





DMTH6010LPDQ Document number: DS38517 Rev. 4 - 2



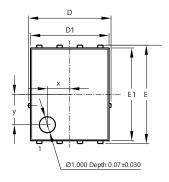


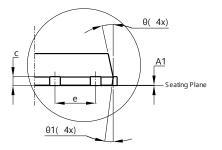


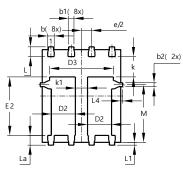
## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version. Site1:

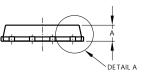
PowerDI5060-8 (Type C)





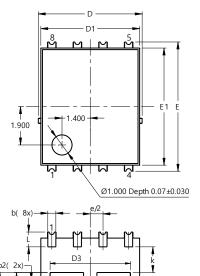


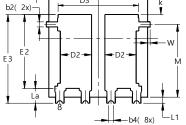
DETAIL A



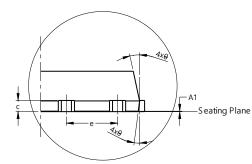
Po	werDI506	50-8 (Typ	be C)
Dim	Min	Max	Тур
Α	0.90	1.10	1.00
A1	0	0.05	0.02
b	0.33	0.51	0.41
b1	0.300	0.366	0.333
b2	0.20	0.35	0.25
С	0.23	0.33	0.277
D	ļ	5.15 BSC	)
D1	4.85	4.95	4.90
D2	1.40	1.60	1.50
D3	-	-	3.98
Е	(	6.15 BSC	)
E1	5.75	5.85	5.80
E2	3.56 3.76		3.66
е	1.27BSC		
k	-	-	1.27
k1	0.56	-	-
L	0.51	0.71	0.61
La	0.51	0.71	0.61
L1	0.05	0.20	0.175
L4	-	-	0.125
М	3.50	3.71	3.605
х	-	-	1.400
У	-	-	1.900
θ	10°	12°	11°
θ1	6°	8°	7°
Al	l Dimens	sions in	mm

Site2:

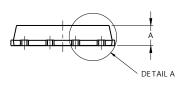




PowerDI5060-8/SWP (Type UXD)



DETAIL A



Ро	PowerDI5060-8/SWP				
	(Type UXD)				
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05			
b	0.30	0.50	0.41		
b2	0.20	0.35	0.25		
b4	(	).25REF			
С	0.230	0.330	0.277		
D	5	.15 BS0	2		
D1	4.70	5.10	4.90		
D2	1.46	1.66	1.55		
D3	3.78	4.18	3.98		
E	6	.40 BS0	C		
E1	5.60	6.00	5.80		
E2	3.46	3.86	3.66		
E2a	4.195	4.595	4.395		
е	1	.27BSC	)		
k	1.05				
L	0.635	0.835	0.735		
La	0.635	0.835	0.735		
L1	0.200	0.400	0.300		
Μ	3.205	4.005	3.605		
W	0.025	0.225	0.125		
θ	10°	12°	11°		
θ1	6°	8°	7°		
All	Dimensi	ions in	mm		

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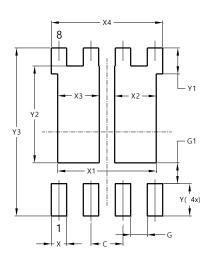


## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site1:

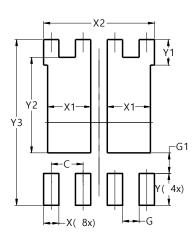
PowerDI5060-8 (Type C)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	3.910		
X2	1.650		
X3	1.650		
X4	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		

Site2:

#### PowerDI5060-8/SWP (Type UXD)



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	1.720		
X2	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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